NSN 5961-00-563-2082

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-563-2082

Inclosure Material:

Metal

Overall Length:

0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 140.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

30.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

98230-on088744 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No

Fiig:

A110a0